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February 18, 2004

Commissioner for Patents P.O.Box 1450 Alexandria, VA 22313-1450

Fr: George O. Saile, Reg. No. 19,572 28 Davis Avenue Poughkeepsie, N.Y. 12603

Subject:

Serial No. 10/724,784 12/01/03

May-Ho Ko

FLASH PROCESS FOR STACKING POLY ETCHING

INFORMATION DISCLOSURE STATEMENT

Enclosed is Form PTO-1449, Information Disclosure Citation In An Application.

The following Patents and/or Publications are submitted to comply with the duty of disclosure under CFR 1.97-1.99 and 37 CFR 1.56.

CERTIFICATE OF MAILING

I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on February ? ? , 2004.

Stephen B. Ackerman, Reg.# 37761

Signature/Date JPB 2/23/0

TSMC-00-932

U.S. Patent 6,165,375 to Yang et al., "Plasma Etching Method," discloses a flash step in an etch process.

U.S. Patent 6,165,861 to Liu et al., "Integrated Circuit Polysilicon Resistor Having a Silicide Extension to Achieve 100% Metal Shielding from Hydrogen Intrusion," discloses a method for a mixed mode product.

The following two U.S. Patents discloses processes for mixed mode products using poly etches:

- 1) U.S. Patent 6,103,622 to Huang, "Silicide Process for Mixed Mode Product with Dual Layer Capacitor and Polysilicon Resistor which is Protected with a Capacitor Protective Oxide During Silicidation of FET Device."
- 2) U.S. Patent 6,103,621 to Huang, "Silicide Process for Mixed Mode Product with Dual Layer Capacitor which is Protected by a Capacitor Protective Oxide During Silicidation of FET Device."

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Stephen B. Ackerman,

Reg. No. 37761

Form PTO-1449 Doctor Humber (Opecner) tsmc-00-932 INFORMATION DISCLOSURE CITATION Applicant IN AN APPLICATION FHOR Date Oroup Art Unit (Uso soveral shoots if necessary) U. S'. PATENT DOCUMENTS EXAMINER IN TAL DOCUMENT HUMBER DATE HAME CLASS JUNO DATE BUSCLUE 67 216 382 438 652 438 FOREIGN PATENT DOCUMENTS Translation DOCUMENT NUMBER DATE COUNTRY CUSS SUBCLASS YES

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EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP § 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to the applicant

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